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March 2001 Revised January 2005

NC7WZ240

TinyLogic® UHS Dual Inverting Buffer with 3-STATE Outputs

General Description

The NC7WZ240 is a Dual Inverting Buffer with independent active LOW enables for the 3-STATE outputs. The Ultra High Speed device is fabricated with advanced CMOS technology to achieve superior switching performance with high output drive while maintaining low static power dissipation over a broad $\rm V_{CC}$ operating range. The device is specified to operate over the 1.65V to 5.5V $\rm V_{CC}$ operating range. The inputs and outputs are high impedance when $\rm V_{CC}$ is 0V. Inputs tolerate voltages up to 5.5V independent of $\rm V_{CC}$ operating range. Outputs tolerate voltages above $\rm V_{CC}$ when in the 3-STATE condition.

Features

- Space saving US8 surface mount package
- MicroPak™ Pb-Free leadless package
- Ultra High Speed; t_{PD} 2.3 ns typ into 50 pF at 5V V_{CC}
- High Output Drive; ±24 mA at 3V V_{CC}
- Broad V_{CC} Operating Range: 1.65V to 5.5V
- \blacksquare Matches the performance of LCX when operated at 3.3V $\rm V_{CC}$
- Power down high impedance inputs/outputs
- Overvoltage tolerant inputs facilitate 5V to 3V translation
- Outputs are overvoltage tolerant in 3-STATE mode
- Proprietary noise/EMI reduction circuitry implemented

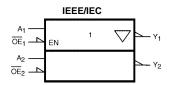
Ordering Code:

		Product		
Order	Package	Code	Package Description	Supplied As
Number	Number	Top Mark		
NC7WZ240K8X	MAB08A	WZ40	8-Lead US8, JEDEC MO-187, Variation CA 3.1mm Wide	3k Units on Tape and Reel
NC7WZ240L8X	MAC08A	U7	Pb-Free 8-Lead MicroPak, 1.6 mm Wide	5k Units on Tape and Reel

Pb-Free package per JEDEC J-STD-020B.

 $\label{eq:total_cond} \mbox{TinyLogic@ is a registered trademark of Fairchild Semiconductor Corporation.} \\ \mbox{MicroPak}^{\mbox{\tiny TM}} \mbox{ is a trademark of Fairchild Semiconductor Corporation.} \\$

Logic Symbol



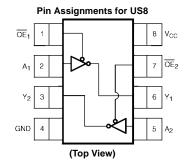
Pin Descriptions

Pin Names	Description
OE _n	Enable Inputs for 3-STATE Outputs
A _n	Inputs
Y _n	3-STATE Outputs

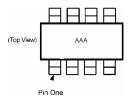
Function Table

Inp	Output	
OE	A _n	Y _n
L	L	Н
L	Н	L
Н	L	Z
Н	Н	Z
H = HIGH Logic Level	L = LOW Logic Leve	Z = 3-STATE

Connection Diagrams



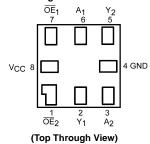
Pin One Orientation Diagram



AAA represents Product Code Top Mark - see ordering code

Note: Orientation of Top Mark determines Pin One location. Read the top
product code mark left to right, Pin One is the lower left pin (see diagram).

Pad Assignment for MicroPak



Absolute Maximum Ratings(Note 1)

-0.5V to +7.0V Supply Voltage (V_{CC}) DC Input Voltage (V_{IN}) (Note 2) -0.5V to +7.0V DC Output Voltage (V_{OUT}) -0.5V to +7.0V

DC Input Diode Current (I_{IK})

 $@V_{IN} < 0V$

DC Output Diode Current (I_{OK}) $@V_{OUT} < 0V$

-50 mA DC Output Source/Sink Current (I_{OUT}) \pm 50 mA DC V_{CC}/Ground Current (I_{CC}/I_{GND}) \pm 100 mA Storage Temperature Range (T_{STG}) $-65^{\circ}C$ to $+150^{\circ}C$

Junction Lead Temperature under Bias (T_J)

Junction Lead Temperature (T_L)

(Soldering, 10 seconds) 250 mW Power Dissipation (P_D) @ $+85^{\circ}$ C

Recommended Operating Conditions (Note 3)

Supply Voltage Operating (V_{CC}) 1.65V to 5.5V 1.5V to 5.5V Supply Voltage Data Retention (V_{CC}) 0V to 5.5V Input Voltage (V_{IN})

-50 mA Output Voltage (V_{OUT})

+150°C

0V to $V_{\mbox{\footnotesize CC}}$ Active State 3-STATE 0V to 5.5V Operating Temperature (T_A) -40°C to +85°C

Input Rise and Fall Time (t_r, t_f)

 V_{CC} @ 1.8V, 0.15V, 2.5V \pm 0.2V 0 ns/V to 20 ns/V V_{CC} @ $3.3V \pm 0.3V$ 0 ns/V to 10 ns/V V_{CC} @ $5.0V \pm 0.5V$ 0 ns/V to 5 ns/V +260°C Thermal Resistance (θ_{JA}) 250°C/W

Note 1: Absolute maximum ratings are DC values beyond which the device may be damaged or have its useful life impaired. The datasheet specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. Fairchild does not recommend operation outside datasheet specifi-

Note 2: The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

Note 3: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{CC}	T _A = +25°C		$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units	Conditions		
Symbol	Parameter	(V)	Min Typ		Max	Min	Max	Units	Conditions	
V _{IH}	HIGH Level Input Voltage	1.65 to 1.95	0.75 V _{CC}			0.75 V _{CC}		V		
		2.3 to 5.5	0.7 V _{CC}			0.7 V _{CC}		, v		
V _{IL}	LOW Level Input Voltage	1.65 to 1.95			0.25 V _{CC}		0.25 V _{CC}	V		
		2.3 to 5.5			0.3 V _{CC}		0.3 V _{CC}	ľ		
V _{OH}	HIGH Level Output Voltage	1.65	1.55	1.65		1.55				
		2.3	2.2	2.3		2.2		V	$V_{IN} = V_{IH}$	$I_{OH} = -100 \mu A$
		3.0	2.9	3.0		2.9		ľ	or V_{IL}	
		4.5	4.4	4.5		4.4				
		1.65	1.29	1.52		1.29				$I_{OH} = -4 \text{ mA}$
		2.3	1.9	2.15		1.9			$V_{IN} = V_{IH}$	$I_{OH} = -8 \text{ mA}$
		3.0	2.4	2.80		2.4		V	or V_{IL}	$I_{OH} = -16 \text{ mA}$
		3.0	2.3	2.68		2.3				$I_{OH} = -24 \text{ mA}$
		4.5	3.8	4.20		3.8				$I_{OH} = -32 \text{ mA}$
V _{OL}	LOW Level Output Voltage	1.65		0.0	0.10		0.10			
		2.3		0.0	0.10		0.10	V	$V_{IN} = V_{IH}$	$I_{OL} = 100 \mu A$
		3.0		0.0	0.10		0.10	ľ	or V_{IL}	
		4.5		0.0	0.10		0.10			
		1.65		0.08	0.24		0.24			I _{OL} = 4 mA
		2.3		0.10	0.3		0.3			$I_{OL} = 8 \text{ mA}$
		3.0		0.15	0.4		0.4	V		$I_{OL} = 16 \text{ mA}$
		3.0		0.22	0.55		0.55			$I_{OL} = 24 \text{ mA}$
		4.5		0.22	0.55		0.55			$I_{OL} = 32 \text{ mA}$
I _{IN}	Input Leakage Current	0 to 5.5			±0.1		±1	μΑ	$V_{IN} = 5.5V$, GND
l _{OZ}	3-STATE Output Leakage	1.65 to 5.5			±0.5		±5	μΑ	$V_{IN} = V_{IH} c$	or V _{IL}
									$0 \le V_{OUT} \le$	≤ 5.5V
l _{OFF}	Power Off Leakage Current	0.0			1		10	μΑ	V _{IN} or V _{OL}	_{JT} = 5.5V
I _{CC}	Quiescent Supply Current	1.65 to 5.5			1		10	μΑ	$V_{IN} = 5.5V$, GND

Noise Characteristics

Symbol	Parameter	v _{cc}	T _A = ∃	$T_A = +25^{\circ}C$		Conditions	
- Cyllibol	i arameter	(V)	Тур	Max	Units	Conditions	
V _{OLP} (Note 4)	Quiet Output Maximum Dynamic V _{OL}	5.0		1.0	V	C _L = 50 pF	
V _{OLV} (Note 4)	Quiet Output Minimum Dynamic V _{OL}	5.0		1.0	V	C _L = 50 pF	
V _{OHV} (Note 4)	Quiet Output Minimum Dynamic V _{OH}	5.0		4.0	V	C _L = 50 pF	
V _{IHD} (Note 4)	Minimum HIGH Level Dynamic Input Voltage	5.0		3.5	V	C _L = 50 pF	
V _{ILD} (Note 4)	Maximum LOW Level Dynamic Input Voltage	5.0		1.5	V	C _L = 50 pF	

Note 4: Parameter guaranteed by design.

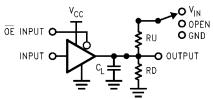
AC Electrical Characteristics

Symbol	Parameter	v _{cc}	T _A = +25°C			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions	Figure	
Cymbol	i ai ailletei	(V)	Min	Тур	Max	Min	Max	Oilles	Conditions	Number	
t _{PLH} ,	Propagation Delay	1.8 ± 0.15	2.0		12.0	2.0	13.0		C _L = 15 pF		
t _{PHL}	A_n to Y_n	2.5 ± 0.2	1.0		7.5	1.0	8.0	ns	$R_D = 1 M\Omega$	Figures	
		3.3 ± 0.3	0.8		5.2	0.8	5.5	113	S1= Open	1, 3	
		5.0 ± 0.5	0.5		4.5	0.5	4.8				
t _{PLH} ,	Propagation Delay	3.3 ± 0.3	1.2		5.7	1.2	6.0		C _L = 50 pF		
t_{PHL}	A_n to Y_n	5.0 ± 0.5	8.0		5.0	8.0	5.3	ns	$R_D = 500\Omega$	Figures 1, 3	
									S1= Open	., -	
t _{OSLH} ,	Output to Output Skew	3.3 ± 0.3			1.0		1.0		C _L = 50 pF	F:	
toshl	(Note 5)	5.0 ± 0.5			8.0		8.0	ns	$R_D = 500\Omega$	Figures 1, 3	
									S1= Open	., -	
t _{PZL} ,	Output Enable Time	1.8 ± 0.15	3.0		14.0	3.0	15.0		C _L = 50 pF		
t_{PZH}		2.5 ± 0.2	1.8		8.5	1.8	9.0		R_D , $R_U = 500 \Omega$		
		3.3 ± 0.3	1.2		6.2	1.2	6.5	ns	$S1 = GND \text{ for } t_{PZH}$	Figures 1, 3	
		5.5 ± 0.5	0.8		5.5	0.8	5.8		$S1 = V_I \text{ for } t_{PZL}$, -	
									$V_I = 2 \times V_{CC}$		
t _{PLZ} ,	Output Disable Time	1.8 ± 0.15	2.5		12.0	2.5	13.0		C _L = 50 pF		
t_{PHZ}		2.5 ± 0.2	1.5		8.0	1.5	8.5		R_D , $R_U = 500 \Omega$	F:	
		3.3 ± 0.3	0.8		5.7	0.8	6.0	ns	$S1 = GND \text{ for } t_{PZH}$	Figures 1, 3	
		5.0 ± 0.5	0.3		4.7	0.3	5.0		$S1 = V_I \text{ for } t_{PZL}$, -	
									$V_I = 2 \times V_{CC}$		
C _{IN}	Input Capacitance	0		2.5				pF			
C_{OUT}	Output Capacitance	5.0		4				Pi			
C _{PD}	Power Dissipation Capacitance	3.3		10				pF	(Note 6)	Figure 2	
		5.0		12				Pi	(14016-0)	i igule 2	

 $\textbf{Note 5:} \ \text{Parameter guaranteed by design.} \ t_{OSLH} = |t_{PLHmax} - t_{PLHmin}|; \ t_{OSHL} = |t_{PHLmax} - t_{PHLmin}|.$

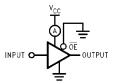
Note 6: C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (See Figure 2.) C_{PD} is related to I_{CCD} dynamic operating current by the expression: $I_{CCD} = (C_{PD})(V_{CC})(f_{|N}) + (I_{CC}static)$.

AC Loading and Waveforms



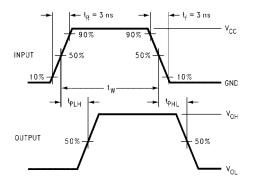
C_L includes load and stray capacitance Input PRR = 1.0 MHz; $t_w = 500 \text{ ns}$

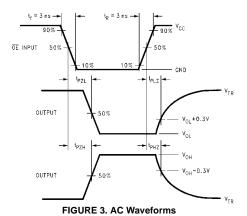
FIGURE 1. AC Test Circuit



 $Input = AC \ Waveform; \ t_r = t_f = 1.8 \ ns;$ PRR = 10 MHz; Duty Cycle = 50%

FIGURE 2. I_{CCD} Test Circuit

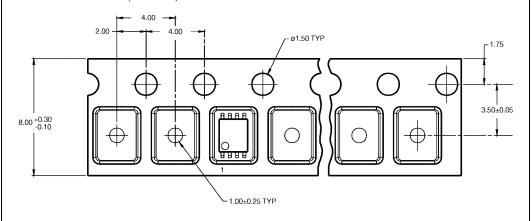




Tape and Reel Specification Tape Format for US8

Tape I offiliat for 05	U .			
Package	Таре	Number	Cavity	Cover Tape
Designator	Section	Cavities	Status	Status
	Leader (Start End)	125 (typ)	Empty	Sealed
K8X	Carrier	3000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

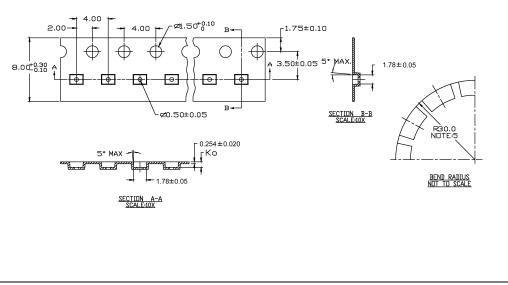
TAPE DIMENSIONS inches (millimeters)



Tape Format for MicroPak

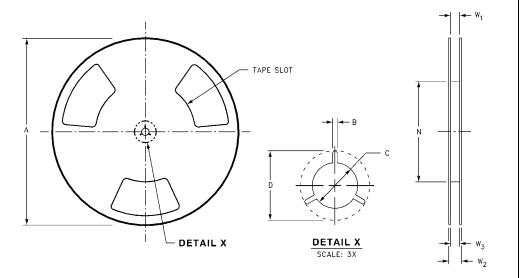
Tape Termation				
Package	Tape	Number	Cavity	Cover Tape
Designator	Section	Cavities	Status	Status
	Leader (Start End)	125 (typ)	Empty	Sealed
L8X	Carrier	3000	Filled	Sealed
	Trailer (Hub End)	75 (typ)	Empty	Sealed

TAPE DIMENSIONS inches (millimeters)



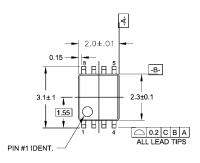
Tape and Reel Specification (Continued)

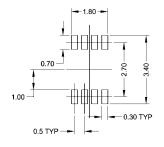
REEL DIMENSIONS inches (millimeters)



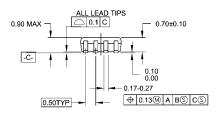
Tape Size	Α	В	С	D	N	W1	W2	W3
8 mm	7.0	0.059	0.512	0.795	2.165	0.331 + 0.059/-0.000	0.567	W1 + 0.078/-0.039
0 111111	(177.8)	(1.50)	(13.00)	(20.20)	(55.00)	(8.40 + 1.50/-0.00)	(14.40)	(W1 + 2.00/-1.00)

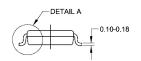
Physical Dimensions inches (millimeters) unless otherwise noted

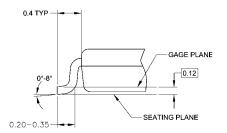




LAND PATTERN RECOMMENDATION







NOTES:

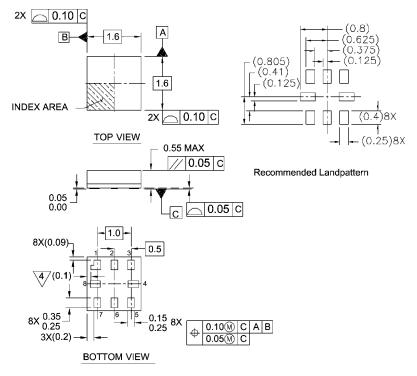
- A. CONFORMS TO JEDEC REGISTRATION MO-187 B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D. DIMENSIONS AND TOLERANCES PER ANSI Y14.5M, 1982.

DETAIL A

MAB08AREVC

8-Lead US8, JEDEC MO-187, Variation CA 3.1mm Wide Package Number MAB08A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Notes:

- 1. PACKAGE CONFORMS TO JEDEC MO-255 VARIATION UAAD
- 2. DIMENSIONS ARE IN MILLIMETERS
- 3. DRAWING CONFORMS TO ASME Y.14M-1994
- 4/PIN 1 FLAG, END OF PACKAGE OFFSET.

MAC08AREVC

Pb-Free 8-Lead MicroPak, 1.6 mm Wide Package Number MAC08A

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- A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

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